

Symbol	Parameter		Ratings	Units	
V _{DS}	Drain to Source Voltage		25	V	
V _{GS}	Gate to Source Voltage		±20	V	
	Drain Current -Continuous (Package Limited)		35		
I _D	-Continuous (Die Limited)		98	A	
	-Pulsed	(Note 1)	305		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	91	mJ	
PD	Power Dissipation		88	W	
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C	
Therma	I Characteristics				
Reic	Thermal Resistance, Junction to Case TO 252, TO 251		1.7	°C/W	

R_{0JA}Thermal Resistance, Junction to Ambient TO-252, 1in² copper pad areaPackage Marking and Ordering Information

Thermal Resistance, Junction to Ambient TO_252, TO_251

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8796	FDD8796	TO-252AA	13"	16mm	2500 units
FDU8796	FDU8796	TO-251AA	N/A (Tube)	N/A	75 units
FDU8796	FDU8796_F071	TO-251AA	N/A (Tube)	N/A	75 units

 $R_{\theta JA}$

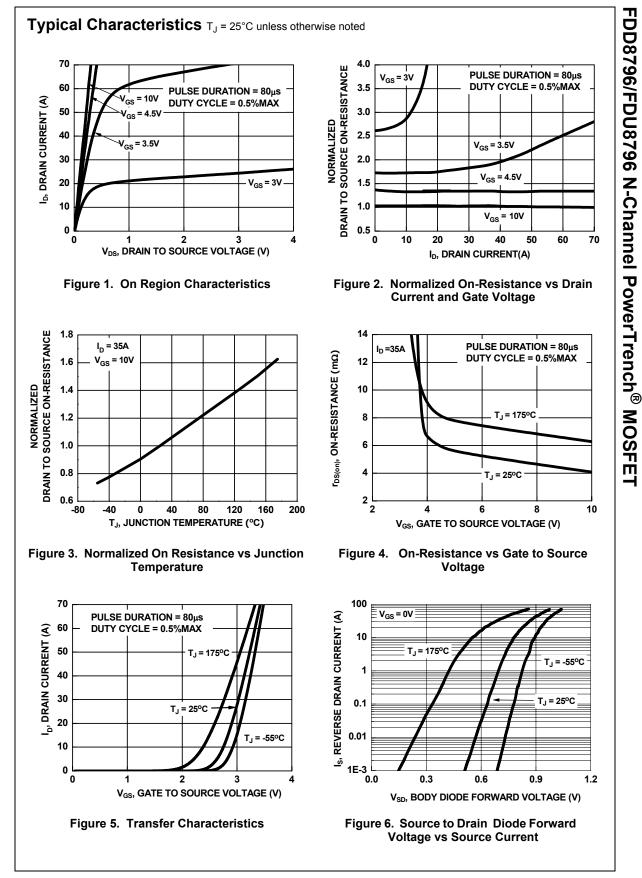
°C/W

°C/W

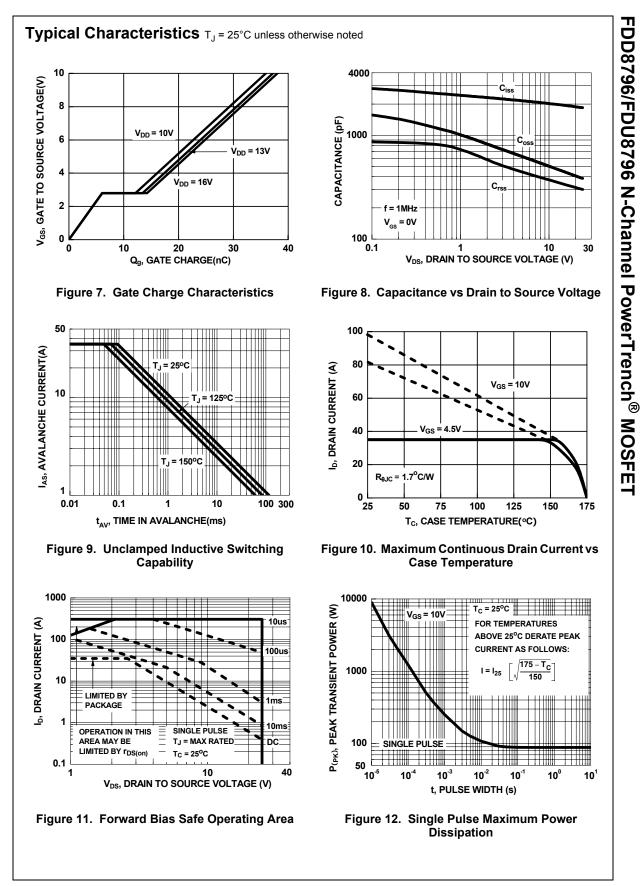
100

52

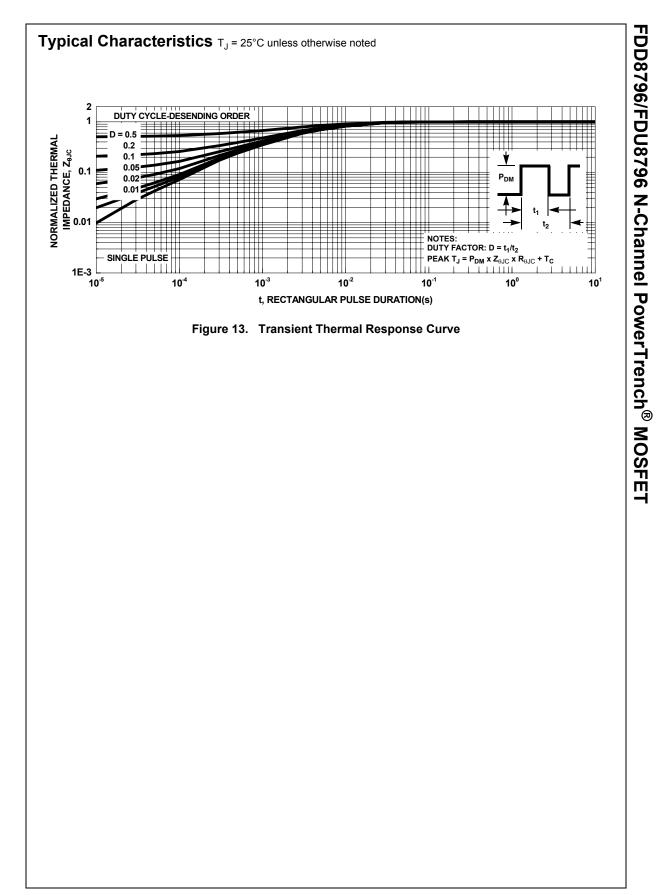
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	25			V
ΔB _{VDSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		7		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 20V$ $V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			1 250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$			±100	nA
	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.2	1.8	2.5	V
$\Delta V_{GS(th)} \Delta T_J$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		-6.7		mV/°C
·		V _{GS} = 10V, I _D = 35A		4.5	5.7	
r _{DO(11)}	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 35A		6.0	8.0	mΩ
DS(on)		V _{DS} = 10V, I _D = 35A T _J = 175°C	6.9		9.5	- 1152
Dynamic	Characteristics	•				
C _{iss}	Input Capacitance			1960	2610	pF
C _{oss}	Output Capacitance	— V _{DS} = 13V, V _{GS} = 0V, — f = 1MHz		455	605	pF
C _{rss}	Reverse Transfer Capacitance			315	475	pF
R _G	Gate Resistance	f = 1MHz		1.1		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			10	20	ns
t _r	Rise Time	V _{DD} =13V, I _D = 35A		24	39	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10V, R_{GS} = 20 Ω		99	158	ns
t _f	Fall Time			57	91	ns
Qg	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$ $I_{D} = 35A,$		37	52	nC
Q _g	Total Gate Charge	$V_{GS} = 0 \text{ to } 5V$ $V_{DD} = 13V,$		19	27	nC
Q _{gs}	Gate to Source Gate Charge	$I_{\rm D} = 35 {\rm A},$ $I_{\rm g} = 1.0 {\rm mA}$		6		nC
Q _{gd}	Gate to Drain Charge			6		nC
Drain-Sou	urce Diode Characteristics	- · · · ·				
V	Source to Drain Diade Valtage	V _{GS} = 0V, I _S = 35A		0.9	1.25	V
V _{SD}	Source to Drain Diode Voltage	V _{GS} = 0V, I _S = 15A		0.8	1.0	V
t _{rr}	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs		30	45	ns
Q _{rr}	Reverse Recovery Charge	I _F = 35A, di/dt = 100A/μs		23	35	nC

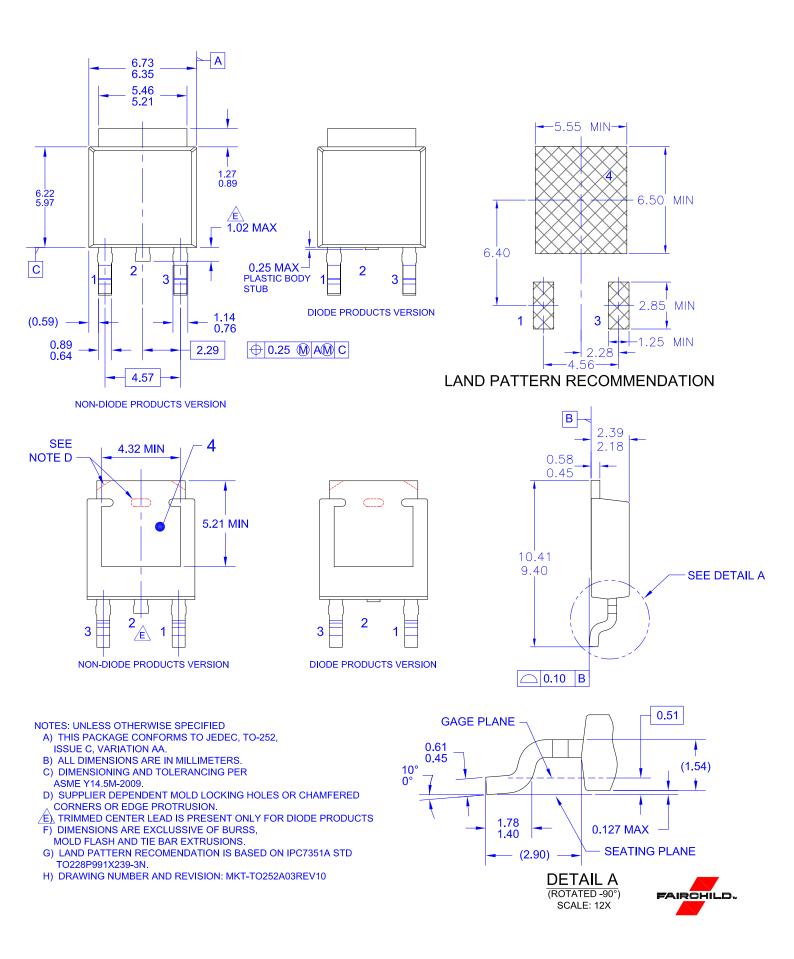


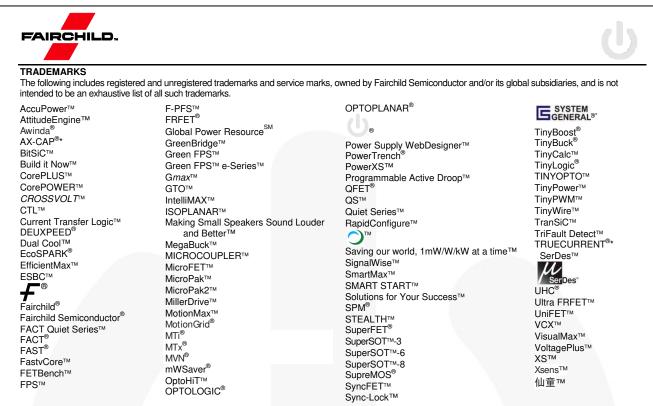
FDD8796/FDU8796 Rev. 1.1



FDD8796/FDU8796 Rev. 1.1







* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is automative of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms				
Datasheet Identification	Product Status	Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 175